NSN 5962-01-189-1045

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches	and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dise	ipation Rating:
739.0 milliwatts	
Operating Tempuratu	re Range:
-55.0/+125.0 degrees of	elsius
Storage Tempurature	Range:
-65.0/+150.0 degrees of	elsius
End Application:	
Integrated automatic d	etection and tracking system an/sys-1
Features Provided:	
Hermetically sealed an	d monolithic and 3-state output and high impedance and programmable
Inclosure Material:	
Ceramic and glass	
Inclosure Configurati	on:
Dual-in-line	
Output Logic Form:	
Transistor-transistor lo	yic
Input Circuit Pattern:	
10 input	
Case Outline Source	And Designator:
D-2 mil-m-38510	
Terminal Surface Tre	atment:
Solder	
Voltage Rating And T	ype Per Characteristic:
5.5 volts power source	
Time Rating Per Chao	teristic:
75.00 nanoseconds pi	opagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Q	uantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

